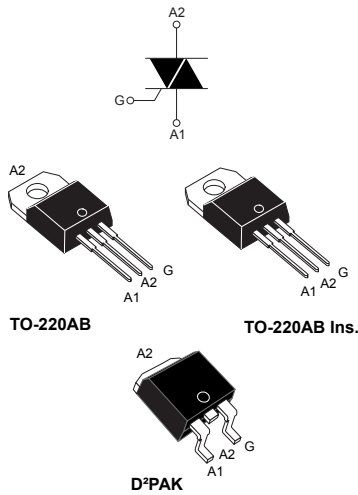


16 A - 600 V H-series Snubberless Triac



Features

- Medium current Triac
- 150 °C max. T_j turn-off commutation
- Low thermal resistance with clip bonding
- Very high 3 quadrant commutation capabilities
- Packages are RoHS (2002/95/EC) compliant
- UL certified (ref. file E81734)

Application

The 600 V T1635H and T1650H are especially designed to operate in high power density or universal motor applications such as vacuum cleaner, coffee brewers, and inrush current limiter for inverter based home appliances.

Description

Available in through-hole or surface mount packages, these Triac series are suitable for general purpose mains power ac switching.

These 20 A Triacs provide a very high switching capability up to junction temperatures of 150 °C.

The heatsink can be reduced, compared to traditional Triacs, according to the high performance at given junction temperatures.

By using an internal ceramic pad, the TO-220AB insulated version provide voltage insulation (rated at 2500 V_{RMS}).

The surface mount D²PAK package enables compact SMD based designs for automated manufacturing.

Product status link

T1635H-6I, T1635H-6T, T1635H-6G,
T1650H-6I, T1650H-6T, T1650H-6G

Product summary

$I_{T(RMS)}$	16 A
V_{DRM}/V_{RRM}	600 V
I_{GT}	35 or 50 mA

1 Characteristics

Table 1. Absolute maximum ratings (limiting values)

Symbol	Parameter		Value	Unit	
$I_{T(RMS)}$	RMS on-state current (full sine wave)	D ² PAK, TO-220AB	$T_c = 130\text{ °C}$	16	A
		TO-220AB Ins.	$T_c = 113\text{ °C}$		
I_{TSM}	Non repetitive surge peak on-state current (full cycle, T_j initial = 25 °C)	f = 50 Hz	t = 20 ms	160	A
		f = 60 Hz	t = 16.7 ms	168	
I^2t	I^2t value for fusing		$t_p = 10\text{ ms}$	169	A ² s
dI/dt	Critical rate of rise of on-state current, $I_G = 2 \times I_{GT}$, tr ≤ 100 ns, f = 100 Hz	f = 120 Hz	$T_j = 150\text{ °C}$	100	A/μs
V_{DSM}/V_{RSM}	Non Repetitive peak off-state voltage	$t_p = 10\text{ ms}$	$T_j = 25\text{ °C}$	$V_{DRM}/V_{RRM} + 100$	V
I_{GM}	Peak gate current	$t_p = 20\text{ μs}$	$T_j = 150\text{ °C}$	4	A
$P_{G(AV)}$	Average gate power dissipation		$T_j = 150\text{ °C}$	1	W
T_{stg}	Storage temperature range			-40 to +150	°C
T_j	Operating junction temperature range			-40 to +150	°C

Table 2. Electrical characteristics ($T_j = 25\text{ °C}$, unless otherwise specified)

Symbol	Test conditions	Quadrants		Value		Unit
				T1635H	T1650H	
$I_{GT}^{(1)}$	$V_D = 12\text{ V}$, $R_L = 33\text{ Ω}$	I - II - III	Max.	35	50	mA
V_{GT}			Max.	1.0		V
V_{GD}	$V_D = V_{DRM}$, $R_L = 3.3\text{ kΩ}$	I - II - III	Min.	0.15		V
I_L	$I_G = 1.2 \times I_{GT}$	I - III	Max.	50	90	mA
		II	Max.	80	110	
$I_H^{(2)}$	$I_T = 500\text{ mA}$, gate open		Max.	35	75	mA
dV/dt ⁽²⁾	$V_D = 2/3 \times V_{DRM}$, gate open	$T_j = 150\text{ °C}$	Min.	1000	1500	V/μs
(dI/dt) _c ⁽²⁾	Without snubber	$T_j = 150\text{ °C}$	Min.	21	28	A/ms

1. Minimum I_{GT} is guaranteed at 20% of I_{GT} max.

2. For both polarities of A2 referenced to A1.

Table 3. Static characteristics

Symbol	Test conditions			Value	Unit
$V_T^{(1)}$	$I_{TM} = 23 \text{ A}$, $t_p = 380 \mu\text{s}$	$T_j = 25 \text{ }^\circ\text{C}$	Max.	1.5	V
$V_{TO}^{(1)}$	Threshold voltage	$T_j = 150 \text{ }^\circ\text{C}$	Max.	0.80	V
$R_D^{(1)}$	Dynamic resistance	$T_j = 150 \text{ }^\circ\text{C}$	Max.	23	m Ω
$I_{DRM}/$ $I_{RRM}^{(2)}$	$V_{DRM} = V_{RRM}$	$T_j = 25 \text{ }^\circ\text{C}$	Max.	5	μA
		$T_j = 150 \text{ }^\circ\text{C}$		4.1	mA
	$V_D = V_R = 400 \text{ V}$, peak voltage	$T_j = 150 \text{ }^\circ\text{C}$	Max.	3.5	mA
		$T_j = 150 \text{ }^\circ\text{C}$	Max.	3.0	

1. For both polarities of A2 referenced to A1.

2. $t_p = 380 \mu\text{s}$

Table 4. Thermal resistance

Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	Junction to case (AC)	D ² PAK, TO-220AB	1.15	$^\circ\text{C/W}$
		TO-220AB Ins.	2.1	
$R_{th(j-a)}$	Junction to ambient ($S_{cu} = 2 \text{ cm}^2$)	D ² PAK, TO-220AB	45	$^\circ\text{C/W}$
		TO-220AB Ins.	60	

1.1 Characteristics (curves)

Figure 1. Maximum power dissipation versus on-state RMS current

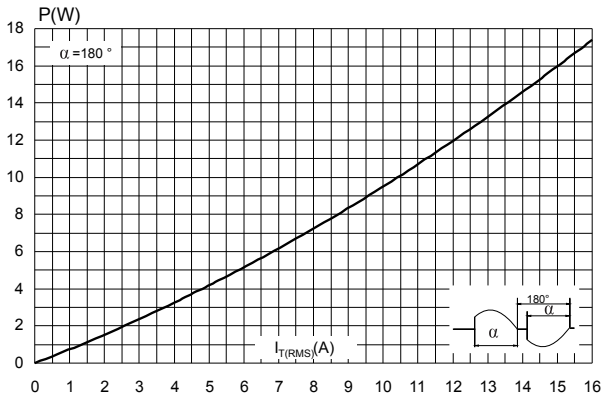


Figure 2. On-state RMS current versus case temperature

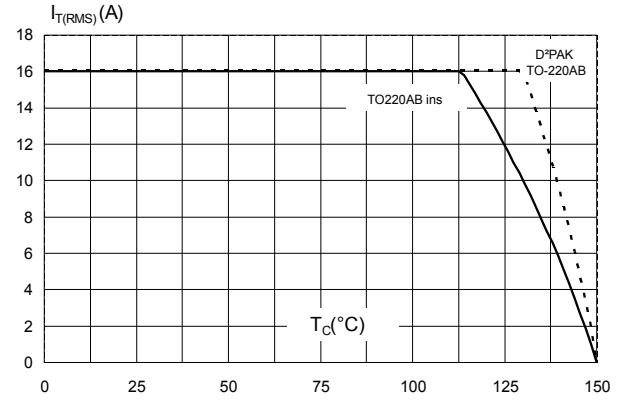


Figure 3. On-state RMS current versus ambient temperature

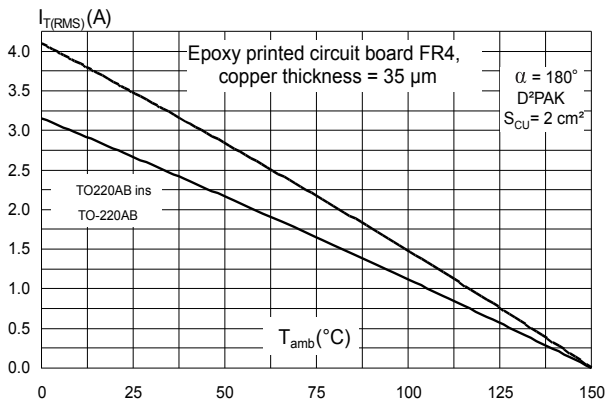


Figure 4. Variation of thermal impedance versus pulse duration

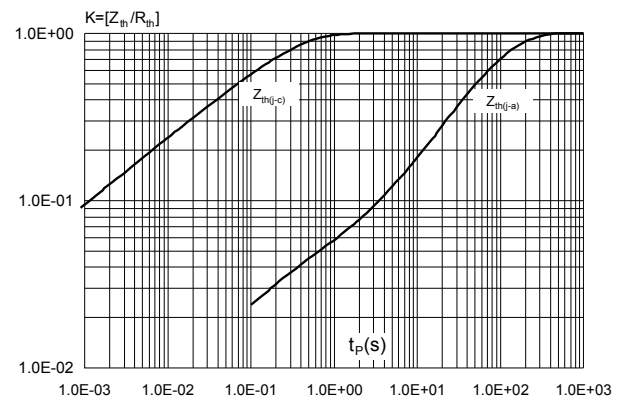


Figure 5. On-state characteristics (maximum values)

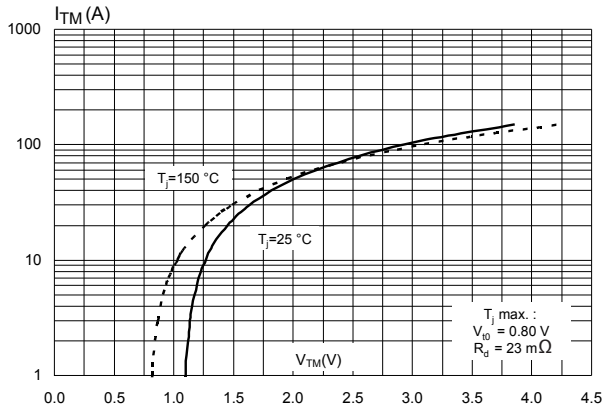


Figure 6. Surge peak on-state current versus number of cycles

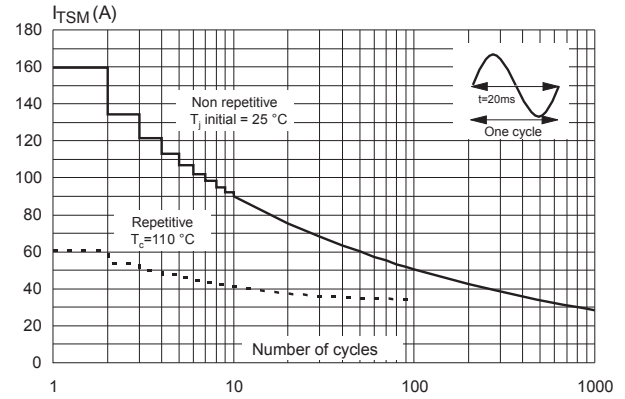


Figure 7. Non repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10$ ms

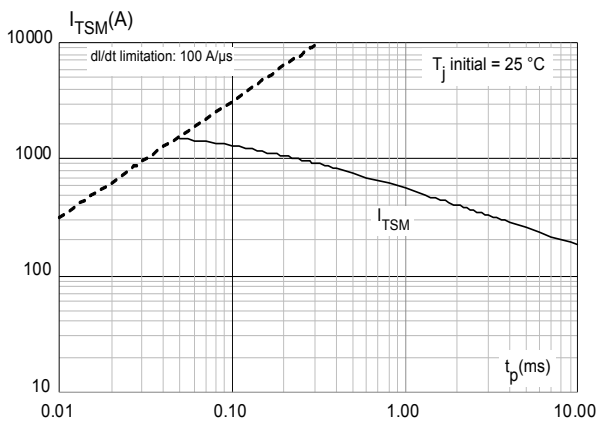


Figure 8. Relative variation of I_{GT}, I_H, I_L vs junction temperature (typical values)

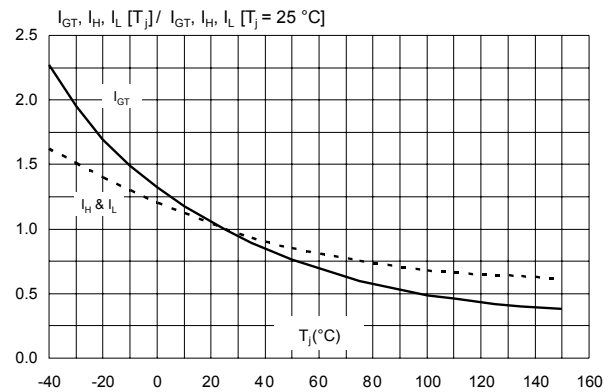


Figure 9. Relative variation of critical rate of decrease of main current $(di/dt)_c$ versus reapplied $(dV/dt)_c$

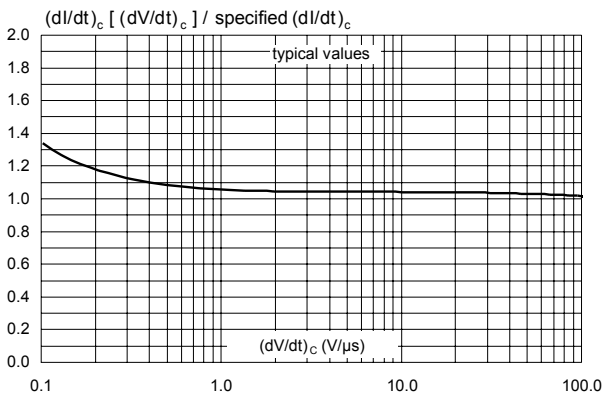


Figure 10. Relative variation of critical rate of decrease of main current versus junction temperature

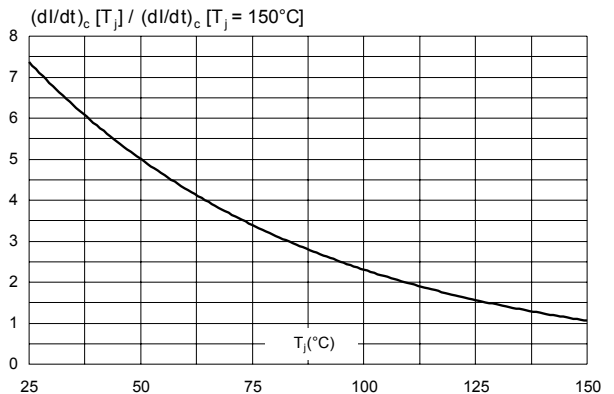


Figure 11. Leakage current versus junction temperature for different values of blocking voltage (typical values)

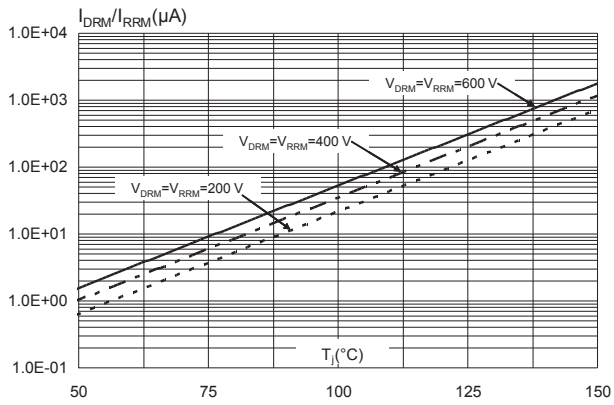


Figure 12. Thermal resistance junction to ambient versus copper surface under tab

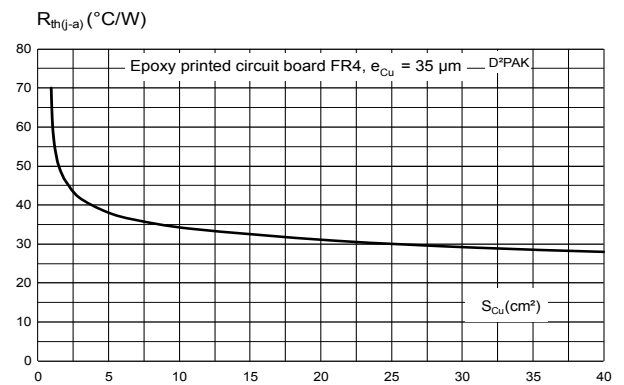


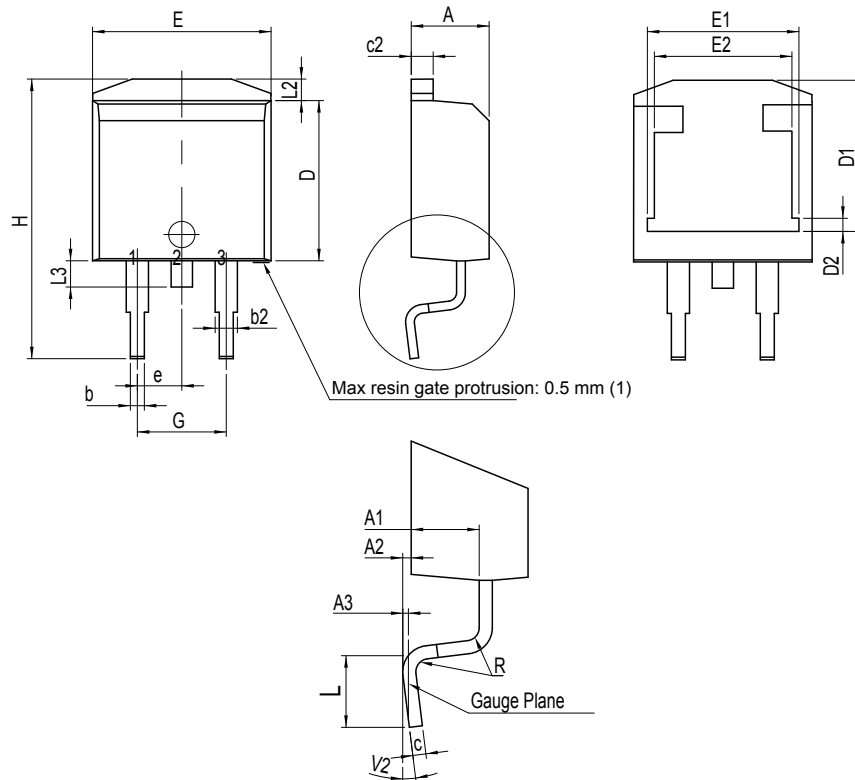
Table 5. TO-220AB package mechanical data

Ref.	Dimensions					
	Millimeters			Inches ⁽¹⁾		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	15.20		15.90	0.5984		0.6260
a1		3.75			0.1476	
a2	13.00		14.00	0.5118		0.5512
B	10.00		10.40	0.3937		0.4094
b1	0.61		0.88	0.0240		0.0346
b2	1.23		1.32	0.0484		0.0520
C	4.40		4.60	0.1732		0.1811
c1	0.49		0.70	0.0193		0.0276
c2	2.40		2.72	0.0945		0.1071
e	2.40		2.70	0.0945		0.1063
F	6.20		6.60	0.2441		0.2598
l	3.73		3.88	0.1469		0.1528
L	2.65		2.95	0.1043		0.1161
l2	1.14		1.70	0.0449		0.0669
l3	1.14		1.70	0.0449		0.0669
l4	15.80	16.40	16.80	0.6220	0.6457	0.6614
M		2.6			0.1024	

1. Inch dimensions are for reference only.

2.2 D²PAK package information

Figure 14. D²PAK package outline

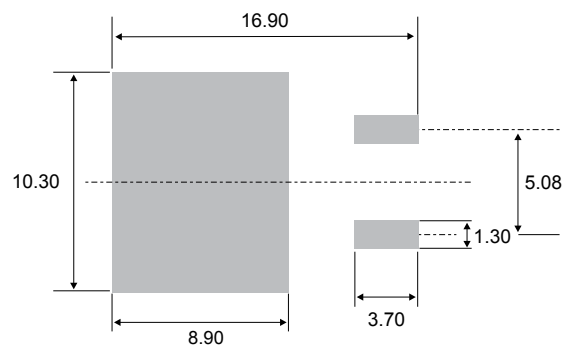


(1) Resin gate is accepted in each of position shown on the drawing, or their symmetrical.

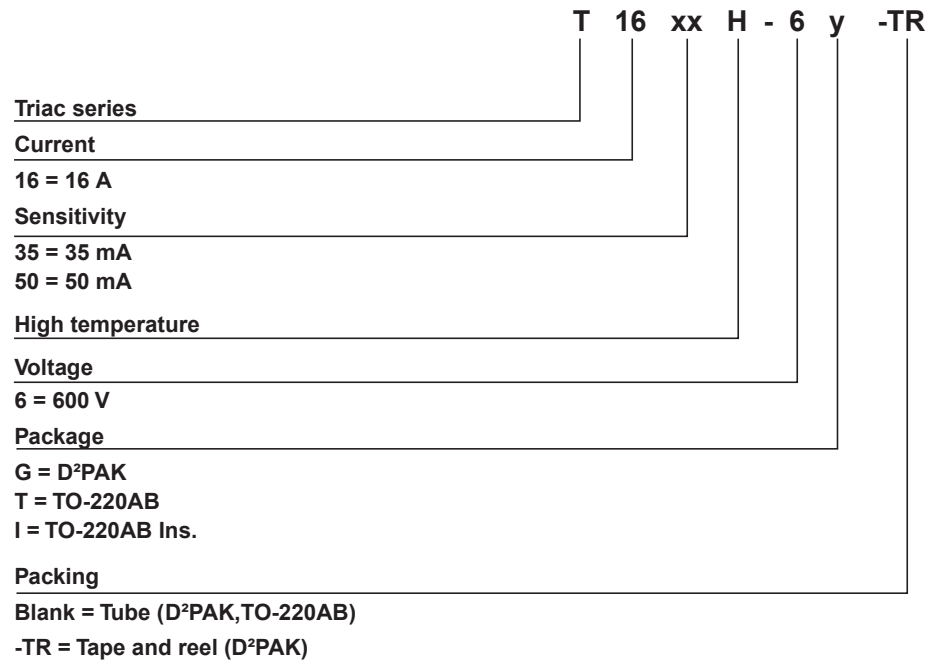
Table 6. D²PAK package mechanical data

Ref.	Dimensions					
	Millimeters			Inches ⁽¹⁾		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.30		4.60	0.1693		0.1811
A1	2.49		2.69	0.0980		0.1059
A2	0.03		0.23	0.0012		0.0091
A3		0.25			0.0098	
b	0.70		0.93	0.0276		0.0366
b2	1.25		1.7	0.0492		0.0669
c	0.45		0.60	0.0177		0.0236
c2	1.21		1.36	0.0476		0.0535
D	8.95		9.35	0.3524		0.3681
D1	7.50		8.00	0.2953		0.3150
D2	1.30		1.70	0.0512		0.0669
e	2.54			0.1		
E	10.00		10.28	0.3937		0.4047
E1	8.30		8.70	0.3268		0.3425
E2	6.85		7.25	0.2697		0.2854
G	4.88		5.28	0.1921		0.2079
H	15		15.85	0.5906		0.6240
L	1.78		2.28	0.0701		0.0898
L2	1.27		1.40	0.0500		0.0551
L3	1.40		1.75	0.0551		0.0689
R		0.40			0.0157	
V2	0°		8°	0°		8°

1. Dimensions in inches are given for reference only

Figure 15. D²PAK recommended footprint (dimensions are in mm)


3 Ordering information

Figure 16. Ordering information scheme

Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
T16xxH-6G	T16xxH 6G	D ² PAK	1.5 g	50	Tube
T16xxH-6G-TR				1000	Tape and reel 13"
T16xxH-6T	T16xxH 6T	TO-220AB	2.3 g	50	Tube
T16xxH-6I	T16xxH 6I	TO-220AB Ins.	2.3 g	50	Tube

Revision history

Table 8. Document revision history

Date	Version	Changes
29-May-2007	1	First issue.
20-Sep-2011	2	Updated: Features, Description and Figure 2.
31-Jan-2014	3	Updated Figure 2, Figure 3, Figure 4, Table 2 and Table 5.
23-Mar-2020	4	Updated Table 1. Absolute maximum ratings (limiting values) and Figure 3. On-state RMS current versus ambient temperature.



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